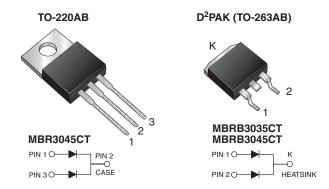


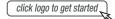
## MBR3045CT, MBRB3035CT, MBRB3045CT

Vishay General Semiconductor

# **Dual Common Cathode Schottky Rectifier**



#### **DESIGN SUPPORT TOOLS**

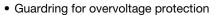




PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	2 x 15 A				
$V_{RRM}$	35 V, 45 V				
I <sub>FSM</sub>	200 A				
$V_{F}$	0.60 V				
T <sub>J</sub> max.	150 °C				
Package	TO-220AB, D <sup>2</sup> PAK (TO-263AB)				
Circuit configurations	Common cathode				

#### **FEATURES**

Power pack





- · Low power loss, high efficiency
- Low forward voltage drop
- High forward surge capability
- · High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for D<sup>2</sup>PAK (TO-263AB) package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB package)
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

#### TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, and polarity protection application.

#### **MECHANICAL DATA**

Case: TO-220AB, D2PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified Base P/NHE3\_X - RoHS-compliant, AEC-Q101 qualified ("\_X" denotes revision code, e.g. A, B, ...)

Terminals: matte tin plated leads, solderable J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

PARAMETER		SYMBOL	MBRB3035CT	MBRB3045CT	UNIT	
Maximum repetitive peak reverse voltage		V <sub>RRM</sub>	35	45		
Working peak reverse voltage		V <sub>RWM</sub>	35	45	V	
Maximum DC blocking voltage		V <sub>DC</sub>	35	45		
Maximum average forward rectified current —	total device	1	30		А	
	per diode	I <sub>F(AV)</sub>	15			
Peak forward surge current 8.3 ms single half superimposed on rated load per diode	sine-wave	I <sub>FSM</sub>	200			
Peak repetitive reverse current per diode at $t_{\rm p}$	<sub>0</sub> = 2.0 μs, 1 kHz	I <sub>RRM</sub>	2.0			
Voltage rate of change (rated V <sub>R</sub> )		dV/dt	10 000		V/µs	
Operating junction temperature range		TJ	-65 to +150		°C	
Storage temperature range		T <sub>STG</sub>	-65 to +175			



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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>C</sub> = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUE	UNIT	
		I <sub>F</sub> = 20 A	T <sub>C</sub> = 125°C	0.60		
Maximum instantaneous forward voltage per diode	V <sub>F</sub> <sup>(1)</sup>	I <sub>F</sub> = 30 A	$T_C = 25^{\circ}C$	0.76	V	
		I <sub>F</sub> = 30 A	T <sub>C</sub> = 125°C	0.72		
Maximum instantaneous reverse current at DC blocking voltage per diode	I <sub>R</sub> <sup>(1)</sup>	Rated V <sub>R</sub>	T <sub>J</sub> = 25 °C	1.0	- mA	
			T <sub>J</sub> = 125 °C	60		

#### Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T <sub>C</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MBR	MBRB	UNIT	
Typical thermal resistance per diode	$R_{ heta JC}$	1.5	1.5	°C/W	

ORDERING IN	IFORMATION (Example)				
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-220AB	MBR3045CT-E3/4W	1.85	4W	50/tube	Tube
TO-263AB	MBRB3045CT-E3/45	1.35	45	50/tube	Tube
TO-263AB	MBRB3045CT-E3/81	1.35	81	800/reel	Tape and reel
TO-263AB	MBRB3045CTHE3_A/P (1)(2)	1.35	Р	50/tube	Tube
TO-263AB	MBRB3045CTHE3_A/I (1)(2)	1.35	I	800/reel	Tape and reel

#### Note

<sup>(1)</sup> AEC-Q101 qualified

<sup>(2) 35</sup> V device available in AEC-Q101 qualified D2PAK (TO-263AB) package only

100



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### **RATINGS AND CHARACTERISTICS CURVES** (T<sub>C</sub> = 25 °C unless otherwise noted)

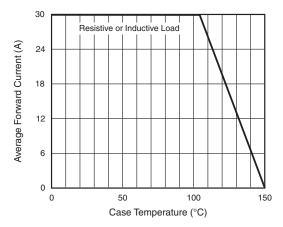


Fig. 1 - Forward Current Derating Curve

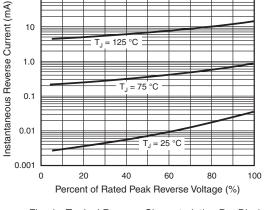


Fig. 4 - Typical Reverse Characteristics Per Diode

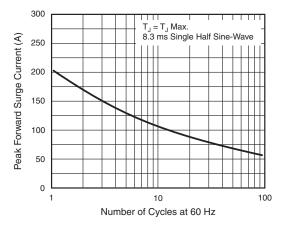


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

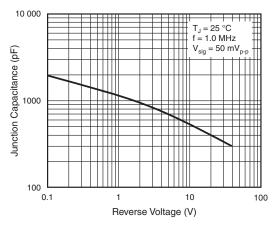


Fig. 5 - Typical Junction Capacitance Per Diode

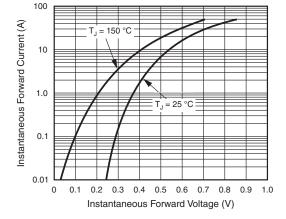


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

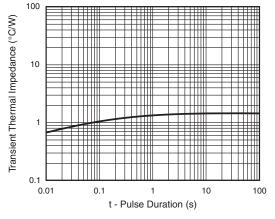
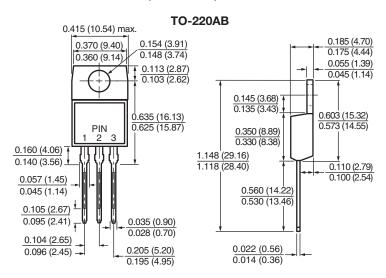


Fig. 6 - Typical Transient Thermal Impedance Per Diode

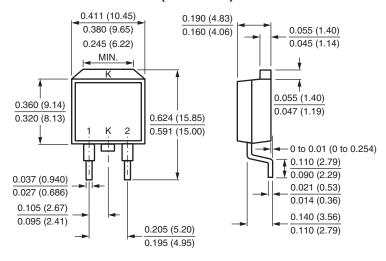
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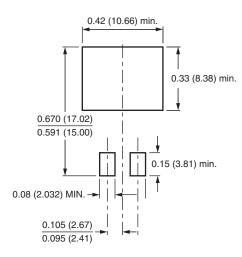
### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



### D<sup>2</sup>PAK (TO-263AB)



#### **Mounting Pad Layout**





## **Legal Disclaimer Notice**

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